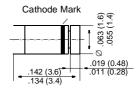


LL4148

FEATURES

- Silicon Epitaxial Planar Diode
- Fast switching diode
- This diode is also available in other case styles including: the DO-35 case with the type designation 1N4148, the SOD-23 case with the type designation 1N4148W, and the SOT-23 case with the type designation

MiniMELF



MECHANICAL DATA

· Case: MiniMELF

• Weight: apprax: 0.05gram

Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

• Ratings at 25°C ambient temperature unless otherwise specified

	Symbol	Value	Unit	
Reverse Voltage	V _R	75	V	
Peak Reverse Voltage	V _{RM}	100	V	
Forward DC current at T _{amb} = 25 °C	I _F	2001)	mA	
Rectified Current (Average) Half Wave Rectification with Resist. Load at T_{amb} = 25 °C and f \geq 50 Hz	I ₀	150 ¹⁾	mA	
Surge Forward Current at t < 1 s and T _j = 25 °C	I _{FSM}	500	mA	
Power Dissipation at T _{amb} = 25 °C	P _{tot}	500 ¹⁾	mW	
Junction Temperature	Tj	175	°C	
Storage Temperature Range	T _S	-65 to +175	°C	

valid provided that electrodes are kept at ambient temperature.

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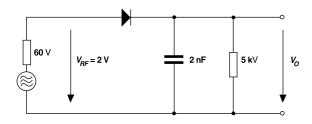


ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Тур.	Max.	Unit
Forward Voltage at I _F = 10 mA	V _F	_	-	1	V
Leakage Current at $V_R = 20 \text{ V}$ at $V_R = 75 \text{ V}$ at $V_R = 20 \text{ V}$, $V_j = 150 \text{ °C}$	I _R I _R I _R	- - -	- - -	25 5 50	nA μA μA
Capacitance at $V_F = V_R = 0$	C _{tot}	_	-	4	pF
Voltage Rise when Switching ON tested with 50 mA Forward Pulses t_p = 0.1 μ s, Rise Time < 30 ns, f_p = 5 to 100 kHz	V _{fr}	-	_	2.5	V
Reverse Recovery Time from I_F = 10 mA to I_R = 1 mA, V_R = 6 V, R_L = 100 Ω	t _{rr}	_	-	4	ns
Thermal Resistance Junction to Ambient Air	R _{thJA}	_	_	0.351)	K/mW
Rectification Efficiency at f = 100 MHz, V _{RF} = 2 V	ην	0.45	_	_	_

¹⁾ Valid provided that electrodes are kept at ambient temperature.



Rectification Efficiency Measurement Circuit

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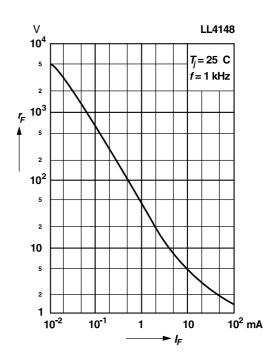


RATINGS AND CHARACTERISTIC CURVES LL4148

Forward characteristics

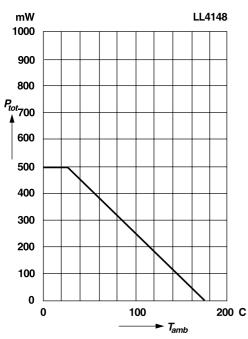
mA LL4148 10³ 10² 10 T_j=100 C/T_j=25 C 11 10⁻² 0 1 2V

Dynamic forward resistance versus forward current

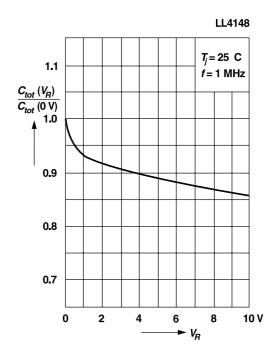


Admissible power dissipation versus ambient temperature

Valid provided that electrodes are kept at ambient temperature



Relative capacitance versus reverse voltage



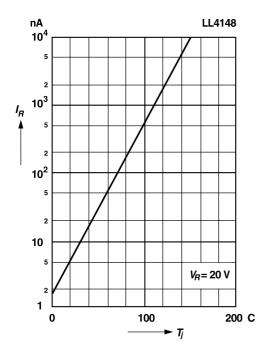
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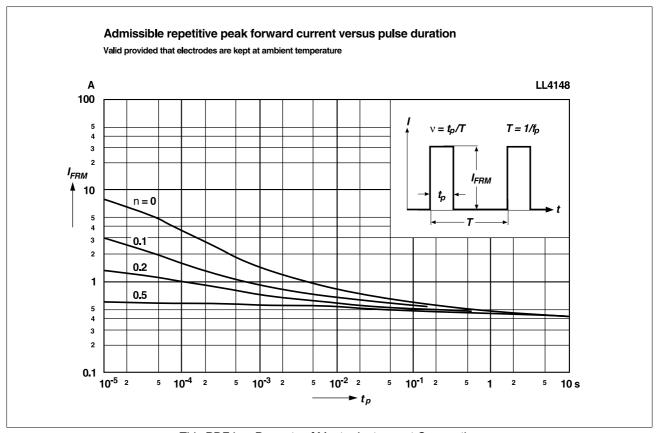
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RATINGS AND CHARACTERISTIC CURVES LL4148

Leakage current versus junction temperature





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